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# AGC amplifier features 60-dB dynamic range

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When processing signals from analog sensors, you frequently encounter wide variations in attenuation among communication channels or sensors. Or, you face situations in which several identical sensors within a supervised system return signals of roughly similar spectral composition

and dynamic range but with considerably different maximum amplitudes. Sometimes, it's possible to predict these and other variations and adjust the gain of preprocessing amplifiers. More frequently, you encounter unpredictable signals and thus lose data associated with nonrepeatable events. In these circumstances, an adaptive preamplifier with AGC (automatic gain control) can prevent measurement-channel saturation and data loss.

AGC preprocessing suppresses the absolute amplitude of a sensed signal while preserving the best possible resolution of individual spectral components' relative amplitudes. The circuit in this Design Idea offers one relatively simple and efficient approach to per-channel AGC. The circuit uses a method of direct low-level signal control using a short-circuited bipolar transistor. In Figure 1, a variable voltage divider comprising a fixed resistance, R<sub>1</sub>, and a variable resistance controls the signal's ac amplitude. The variable resistance comprises the differential resistance of a bipolar transistor,  $Q_1$ , short-circuited

from base to collector. To vary Q<sub>1</sub>'s resistance, you force direct current into the shorted transistor from a current source comprising voltage source  $V_{REG}$  and a high-value resistor, R<sub>2</sub>. To prevent R<sub>2</sub> from affecting the circuit's acvoltage-transfer characteristic, R<sub>2</sub>'s resistance must greatly exceed R<sub>1</sub>'s.







Figure 2 A VI characteristic shows the corresponding differential-resistance graph for a short-circuited BC337-16 transistor. (Note: The -16 denotes a sorted  $h_{FF}$  range of  $100 < h_{FF} < 250$ .)

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For all reasonable values of positive current I—generally, less than the transistor's maximum rated emitter current  $(I_F)$ —transistor  $Q_1$ 's collector-to-emit-

ter saturation voltage is less than its base-emitter threshold voltage, and the transistor operates in the active state. The shorted transistor's VI (voltage-versus-current) characteristic curve strongly resembles that of a PN diode and follows Shockley's Equation except for slightly higher dcvoltage values. That is, the device's voltage variation is proportional to the logarithm of the dc-current variation.

Therefore, the shorted transistor's differential resistance at every dc operating point along the VI curve is inversely proportional to the passing dc current; in other words, the device's differential conductance is directly proportional to the current. Because, in its active state, a common-emitter-connected bipolar transistor's current-amplification factor is typically 100 or more, the differential resistance accurately follows this rule over a broad range of currents.

Thus, varying  $V_{REG}$  in Figure 1 varies the current, I, and controls the  $R_1$ - $Q_1$  voltagedivision ratio. Coupling capacitors  $C_1$  and  $C_2$  separate the

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Figure 3 You can assemble this AGC circuit entirely from discrete components.

circuit's attenuator from the input-signal source and output load. **Figure 2** illustrates a typical small-signal bipolar transistor's short-circuited VI characteristic, showing that you can control differential resistance over at least five decades of range—that is, more than 100 dB.

In a practical circuit, the finite values of  $R_1$  and  $R_2$  limit the control range. For proper operation and to keep the signal's THD (total-harmonic-distortion) factor, k, below 5%, the output-voltage amplitude,  $V_{OUT}$ , should be just a few millivolts. Even with these limitations, this attenuator circuit appears to offer one of the best and simplest AGC circuits.

Figure 3 shows the completed circuit design. The input signal,  $V_{IN}$ , drives buffer stage  $Q_1$ , whose unbypassed emitter resistor,  $R_3$ , serves four purpos-

es. First, it increases  $Q_1$ 's differential output resistance to the approximate value shown in **Equation 1**:

$$R_{D1} \approx \frac{h_{11E} + h_{21E}R_3}{h_{11E}h_{22E}}.$$
 (1)

The increase in the circuit's differential output resistance is so large that the value of  $R_4$ , 27 k $\Omega$ , almost exclusively determines the overall output resistance. Second, leaving  $R_3$  unbypassed reduces  $Q_1$ 's voltage gain to:

$$A_{IC1} = (h_{22E}R_3 - h_{21E})R_4 / (R_3 + R_4)D_{hE} + (2)$$

$$[h_{21E} + 1 - h_{12E} + (R_3 + R_4)]$$

$$R_3 + h_{11E} \approx -R_4 / R_3.$$

This equation simplifies to  $A_{ICI} \approx |R_{4}/R_{3}$ . (Note that  $D_{hE}$  denotes the

determinant  $(h_{11E} \times h_{22E} - h_{12E} \times h_{21E})$ , which this Design Idea includes for theoretical accuracy. However, you can neglect the numerical value of  $D_{hE}$  for modern silicon transistors without significantly affecting the calculation's accuracy.) Third, as **Equation 2** shows, leaving R<sub>3</sub> unbypassed helps linearize the response of Q<sub>1</sub>'s collector currentto-voltage drive. Fourth, Q<sub>1</sub>'s differential base input resistance rises to: R<sub>dBASE</sub> = h<sub>11E</sub> + h<sub>21E</sub> × R<sub>3</sub>, which is larger and less dependent on Q<sub>1</sub>'s instantaneous operating point than h<sub>11E</sub> alone.

In Figure 3, resistor  $R_4$  forms the variable attenuator's fixed resistance, analogous to the upper resistor,  $R_1$ , in Figure 1, and  $Q_6$  forms the attenuator's variable-resistance element. Transistor  $Q_5$  supplies  $Q_6$ 's collector-drive current, and  $Q_5$ 's common-emitter configura-(continued on pg 92)

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tion draws little base current. This approach enables use of a high value for AGC-release time-determining resistor  $R_{17}$ , thus permitting a long AGC-release time. Resistor  $R_{19}$  limits the maximum dc control current through  $Q_5$  and  $Q_6.$ 

The large value of  $C_3$ , when you compare it with  $Q_6$ 's minimum differential resistance-that is, its maximum signal amplitude-at full control, presents negligible reactance to the lowest frequency-signal-spectrum component. A voltage-doubler rectifier comprising  $D_1$  and  $D_2$  extracts a portion of the signal from output stage  $\mathsf{Q}_4$  and produces the control voltage for  $Q_5$ . This arrangement accommodates both polarities of large peak amplitudes of nonsymmetrical signal waveforms. Resistor R<sub>15</sub> determines the AGC's "attack" time. Too small values of R<sub>15</sub> in combination with  $C_6$  can lead to instability by creating a pole in the feedback-transfer function. Resistor R<sub>17</sub> determines the AGC-release time.

To secure good response to high-frequency-signal components, use either Schottky or fast PN silicon diodes for  $D_1$  and  $D_2$ . The dc-coupled complementary cascade comprising  $Q_2$  and  $Q_3$ supplies most of the circuit's voltage gain. A 1-k $\Omega$  resistor,  $R_{14}$ , isolates  $Q_4$ , the output-emitter follower, from the signal-output terminal. If necessary, you can use a lower resistance at  $R_{14}$ , but a large-capacitance connecting cable can provoke  $Q_4$  into parasitic oscillation if  $R_{14}$  is too low.

**Figure 4** shows the circuit's inputversus-output characteristics as measured with a sine-wave signal. The effective AGC range extends from 100-µV-to 100-mV-rms input voltage, a 60-dB dynamic range. Output voltage varies less than 2 dB over this input range, reaching a nominal level of 775 mV rms at a -20-dB- (100-µV-rms) input level. The input's 0-dB point is set arbitrarily at 1-mV-rms input, which corresponds to an 803-mV-rms output. The AGC attack time for a sinusoidal-input-signal step from 0 to 100 mV rms is approximately 0.3 sec, and the AGC







Figure 5 A single-sided pc board accommodates the assembled AGC amplifier.

release from 100-mV-rms input to -20 dB (100  $\mu$ V rms) is approximately 100 sec. Figure 4 also includes a graph of THD versus input voltage. The distortion is well below a 5% THD limit throughout the input-voltage range.

To measure the attenuator's baseline input noise, terminate the input with its nominal 1-k $\Omega$  source resistance. At low input voltages, input stage  $Q_1$ 's noise limits the processed signal's usable dynamic range. The rms noise level is about -38 dB relative to the nominal output for input signals below the AGC

threshold. When the AGC becomes active, the SNR increases in proportion to the AGC reduction. For example, with a 0-dB- (1-mV-rms) input signal, the SNR increases to approximately 60to-1.

If you assemble the circuit using the passive-component values in **Figure 3**, the amplifier's -3-dB bandwidth spans 45 Hz to 35 kHz. At a power-supply voltage of 9V, no-signal current consumption is approximately 12 mA. **Figure 5** shows a photograph of the assembled pc board.**EDN**